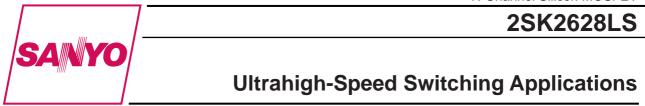
N-Channel Silicon MOSFET

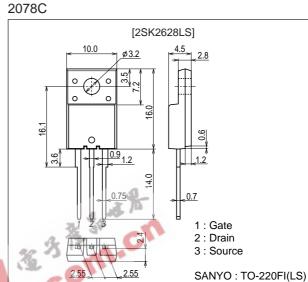


Features

- · Low ON-resistance.
- · Low Qg.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C Conditions Symbol Parameter Ratings Unit Drain-to-Source Voltage VDSS 600 V Gate-to-Source Voltage ±30 V VGSS Drain Current (DC) 6 А ID Drain Current (Pulse) 24 А IDP 2.0 W PD Allowable Power Dissipation Tc=25°C 35 W **Channel Temperature** Tch 150 °C Storage Temperature Tstg -55 to +150 °C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	600			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =600V, V _{GS} =0			1.0	mA
Gate-to-Source Leakage Current	IGSS	VGS=±30V, VDS=0			±100	nA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	3.5		5.5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	2.0	4.0		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=2A, VGS=15V		0.9	1.1	Ω
Marking : K2628				С	ontinued on	next page

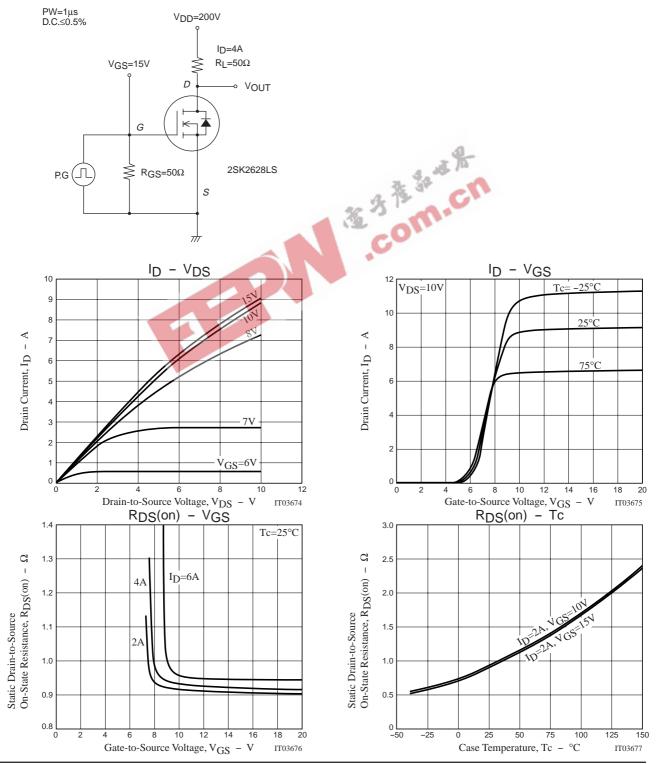
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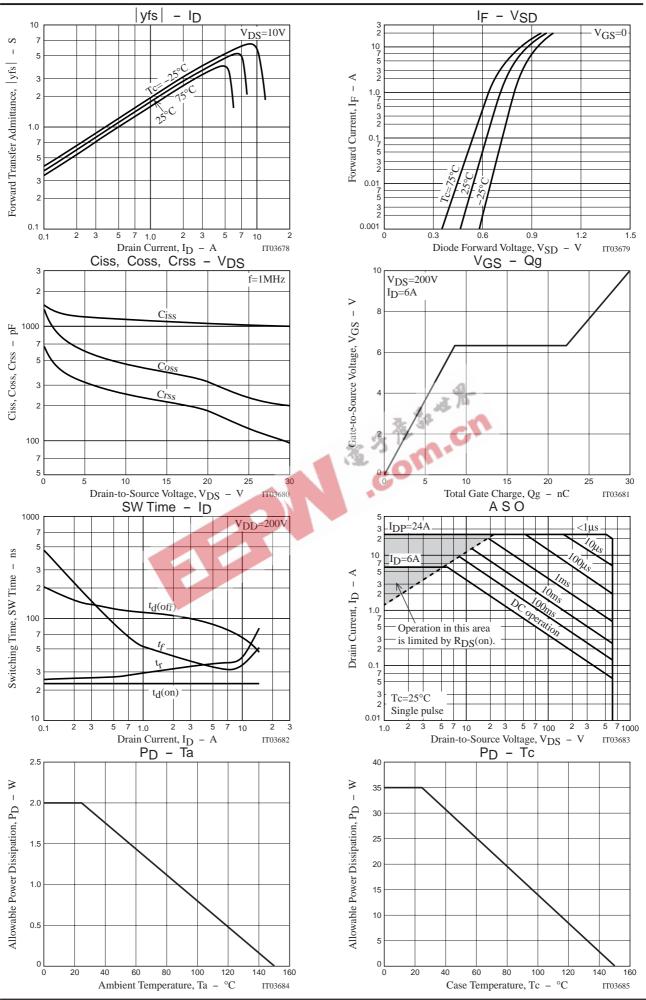
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN Continued from preceding page.

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	VDS=20V, f=1MHz		1050		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		320		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		180		pF
Total Gate Charge	Qg	V _{DS} =200V, V _{GS} =10V, I _D =6A		30		nC
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		23		ns
Rise Time	tr	See specified Test Circuit.		35		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		90		ns
Fall Time	tf	See specified Test Circuit.		35		ns
Diode Forward Voltage	VSD	IS=6A, VGS=0		0.85	1.2	V

Switching Time Test Circuit



No.7082-2/4



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